

Date:- 12th August, 2014

Data Sheet Issue:- 2

Rectifier Diode

Types W6262Z#200 to W6262Z#240

Previous Type No.: SW20-24#XC2850

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	2000-2400	V
V _{RSM}	Non-repetitive peak reverse voltage, (note 1)	2100-2500	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
I _{F(AV)M}	Maximum average forward current, T _{sink} =55°C, (note 2)	6262	Α
I _{F(AV)M}	Maximum average forward current. T _{sink} =100°C, (note 2)	4616	Α
I _{F(RMS)M}	Nominal RMS forward current, T _{sink} =25°C, (note 2)	11327	Α
I _{F(d.c.)}	D.C. forward current, T _{sink} =25°C, (note 3)	9885	Α
I _{FSM}	Peak non-repetitive surge t _p =10ms, V _{rm} =60%V _{RRM} , (note 4)	67	kA
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _{rm} ≤10V, (note 4)	73.7	kA
l ² t	I ² t capacity for fusing t _p =10ms, V _{rm} =60%V _{RRM} , (note 4)	22.4×10 ⁶	A ² s
l ² t	I²t capacity for fusing t _p =10ms, V _{rm} ≤10V, (note 4)	27.2×10 ⁶	A ² s
T _{j op}	Operating temperature range	-40 to +175	°C
T _{stg}	Storage temperature range	-55 to +175	°C

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}$ C is applicable for T_{j} below 25 $^{\circ}$ C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Double side cooled.
- 4) Half-sinewave, 175°C T_j initial.



Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{FM}	Maximum peak forward voltage	-	-	1.18	I _{FM} =6800A	V
V _{T0}	Threshold voltage	-	-	0.73		V
r⊤	Slope resistance	-	-	0.064		mΩ
I _{RRM}	Peak reverse current	-	-	150	Rated V _{RRM}	mA
D	Thermal register as it mation to be stainly	-	-	0.011	Double side cooled	K/W
R _{thJK} Thermal resistance, junction to	Thermal resistance, junction to heatsink	-	-	0.022	Single side cooled	K/W
F	Mounting force	27	-	47	Note 2	kN
W_t	Weight		1.7			kg

Notes:-

- 1) Unless otherwise indicated T_j=175°C.
- 2) For other clamp forces, please consult factory.



Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V _{RRM} V	V _{RSM} V	V _R DC V
20	2000	2100	1250
24	2400	2500	1450

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_i below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{{V_{T0}}^2 + 4 \cdot f\!f^2 \cdot r_T \cdot W_{AV}}}{2 \cdot f\!f^2 \cdot r_T} \qquad \qquad \text{and:} \qquad W_{AV} = \frac{\Delta T}{R_{th}} \\ \Delta T = T_{j\,\text{max}} - T_K$$

Where $V_{T0}=0.73V$, $r_{T}=0.064m\Omega$,

 R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance					
Conduction Angle 6 phase (60°) 3 phase (120°) ½ wave (180°) d.c.					
Square wave Double Side Cooled	0.0144	0.0132	0.0126	0.0116	
Square wave Cathode Side Cooled	0.0262	0.0251	0.0244	0.0235	
Sine wave Double Side Cooled	0.0133	0.0124	0.0115		
Sine wave Cathode Side Cooled	0.0253	0.0244	0.0234		

Form Factors					
Conduction Angle 6 phase (60°) 3 phase (120°) ½ wave (180°) d.c.					
Square wave	2.449	1.732	1.414	1	
Sine wave	2.778	1.879	1.57		



5.2 Calculating V_F using ABCD Coefficients

The forward characteristic I_F vs. V_F, on page 6 is represented in two ways;

- (i) the well established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	175°C Coefficients
Α	0.72773586	0.527673862
В	-4.783379×10 ⁻⁴	2.842161×10 ⁻³
С	1.888101×10 ⁻⁵	3.968936×10 ⁻⁵
D	3.638078×10 ⁻³	4.131844×10 ⁻³



5.3 D.C. Thermal Impedance Calculation

$$r_{t} = \sum_{p=1}^{p=n} r_{p} \cdot \left(1 - e^{\frac{-t}{\tau_{p}}}\right)$$

Where p = 1 to n, n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

 r_{t} = Thermal resistance at time t.

 r_p = Amplitude of p_{th} term.

 τ_p = Time Constant of r_{th} term.

The coefficients for this device are shown in the tables below:

D.C. Double Side Cooled						
Term	m 1 2 3 4					
r_{ρ}	0.01551	2.7827×10 ⁻³	4.2105×10 ⁻³	0.9443×10 ⁻³		
$ au_{ ho}$	10.04275	1.783567	0.2231307	3.428×10 ⁻³		

	D.C. Double Side Cooled						
Term	Term 1 2 3 4 5						
r_{ρ}	6.4176×10 ⁻³	2.7472×10 ⁻³	1.2515×10 ⁻³	0.6336×10 ⁻³	0.59597×10 ⁻³		
$ au_{\mathcal{P}}$	1.785337	0.34595	0.099651	0.014214	2.298151×10 ⁻³		



Curves

Figure 1 – Forward characteristics of Limit device

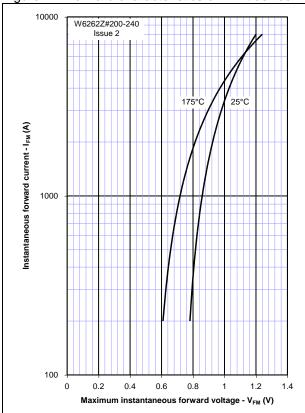


Figure 2 – Transient thermal impedance

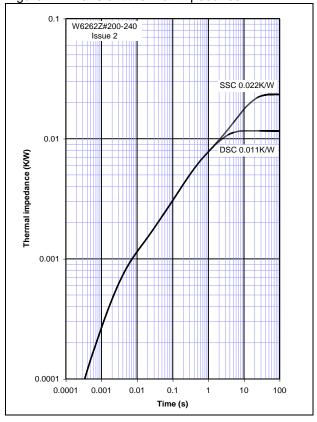


Figure 3 – Maximum surge Rating

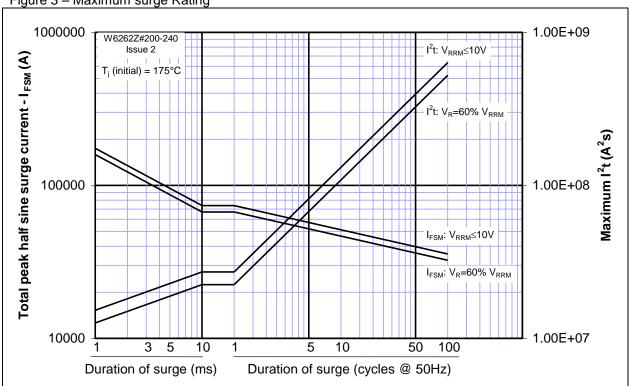




Figure 4 – Forward current vs. Power dissipation – Double Side Cooled

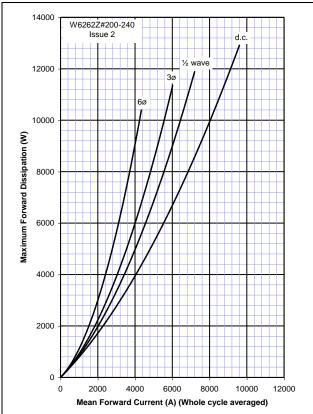


Figure 6 – Forward current vs. Power dissipation – Single Side Cooled

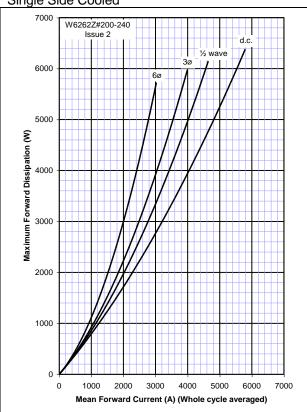


Figure 5 – Forward current vs. Heatsink temperature - Double Side Cooled

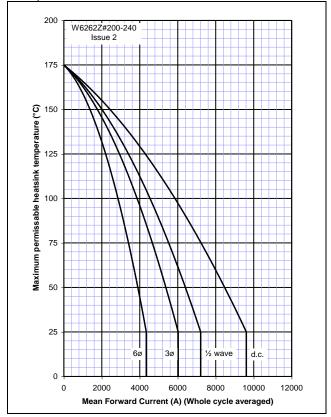
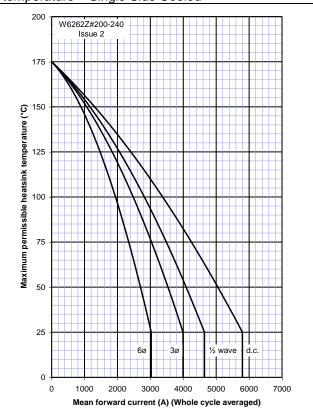
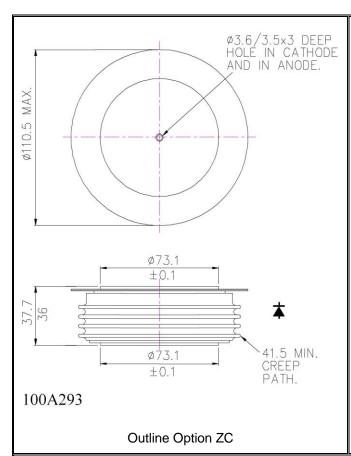


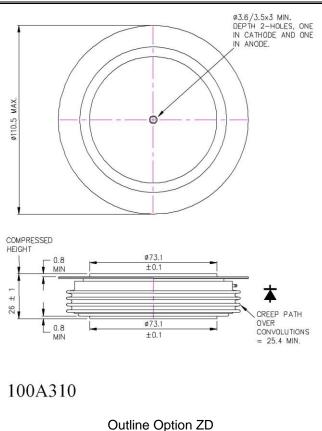
Figure 7 – Forward current vs. Heatsink temperature – Single Side Cooled





Outline Drawing & Ordering Information





	ORDERING INFORMATION (Please quote	(Please quote 10 digit code as below)		
W6262	Z#	**	0	
Fixed Type Code	Fixed outline code ZC = 37.7mm Clamp height, ZD = 26mm Clamp height	Voltage code V _{RRM} /100 20-24	Fixed code	

Order code: W6262ZD240 - 2400V V_{RRM}, 26mm clamp height capsule.

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